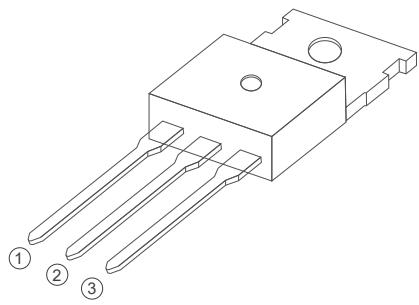


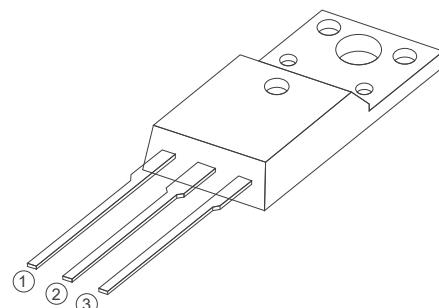
BT139 Series  
16A TRIACs  
4 Quadrants TRIACs



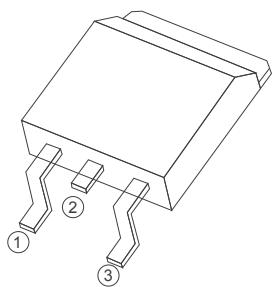
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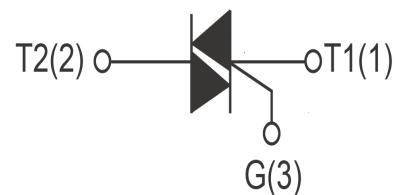
TO-220C



TO-220F Insulated



TO-263



## FEATURES

- > IT(RMS): 16A
- > VGT: 1.5V
- > VDRM VRRM:800V

## APPLICATIONS

Washing machine, vacuums, massager, solid state relay, AC Motor speed regulation and so on.

## Absolute Maximum Ratings (T<sub>j</sub>=25°C unless otherwise specified)

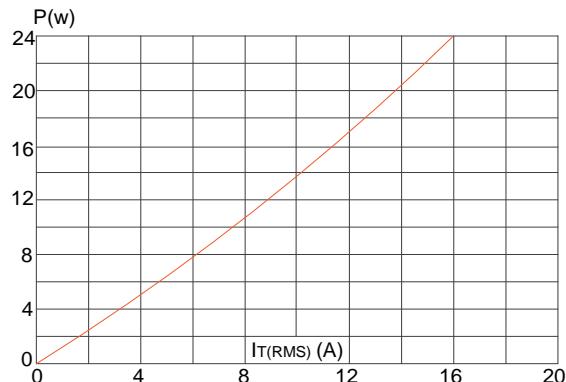
Symbol	Parameter	Conditions	Ratings	Unit
VDRM VRMM	Repetitive Peak Off-State Voltage	BT139-600	600	V
		BT139-800	800	V
IT(RMS)	R.M.S On-State Current	T <sub>c</sub> =110°C	16	A
ITSM	Surge On-State Current	tp=16.7ms/tp=10ms	160/168	A
I <sup>2</sup> t	I <sup>2</sup> t for fusing	T <sub>p</sub> =10ms	144	A <sup>2</sup> s
PG(AV)	Average Gate Power Dissipation	T <sub>j</sub> =125°C	1	W
IGM	Peak Gate Current	T <sub>j</sub> =125°C	4	A
T <sub>j</sub>	Operating Junction Temperature		~40~125	°C
TSTG	Storage Temperature		~40~150	°C

## Electrical Characteristics (T<sub>j</sub>=25°C unless otherwise specified)

Symbol	Parameter	Test Conditions	Value				Unit	
			D	E	F	G		
IDRM	Repetitive Peak Off-State Current	T <sub>j</sub> =25°C	≤5				uA	
		T <sub>j</sub> =125°C	≤1				mA	
IRRM	Repetitive Peak Reverse Current	T <sub>j</sub> =25°C	≤5				uA	
		T <sub>j</sub> =125°C	≤1				mA	
VTM	Forward "on" voltage	IT=35A tp=380us	1.55				V	
VGT	Gate trigger voltage	VD=12V ,RL=30Ω	≤1.5				V	
di/dt	Critical-rate of rise of commutation current.	I,II,III	IG=2XIGT,tr≤100ns,F=100Hz				A /us	
		IV	≥50				A /us	
IGT	Gate trigger current	I,II,III	VD=12V RL=30Ω	≤5	≤10	≤25	≤50	mA
		IV		≤10	≤25	≤70	≤100	mA
IH	Holding current	IT=0.2A	≤10	≤25	≤30	≤60	mA	
VDG	Gate non-trigger voltage	ALL	VD=VDRM ,RL=30Ω ,T <sub>j</sub> =125°C	≥0.2				V
dv/dt	Critical-rate of rise of commutation voltage	T <sub>j</sub> =125°C VD=2/3VDRM Gate open circuit		≥5	≥10	≥25	≥200	V/us
Rth(j-c)	Thermal resistance	Junction to case		1.1				°C/W
Rth(j-a)	Thermal resistance	Junction to ambient		50				°C/W

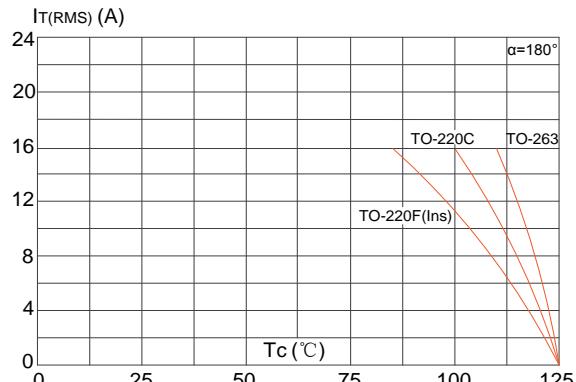
**FIG1**

Maximum power dissipation versus RMS on-state current



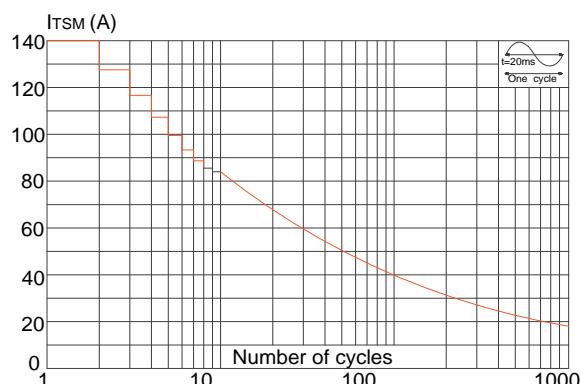
**FIG2**

RMS on-state current versus case temperature



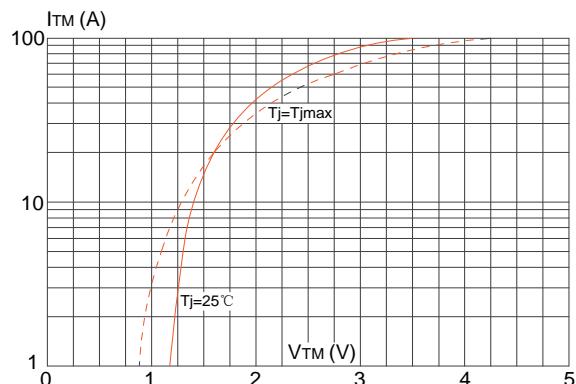
**FIG3**

Surge peak on-state current versus number of cycles



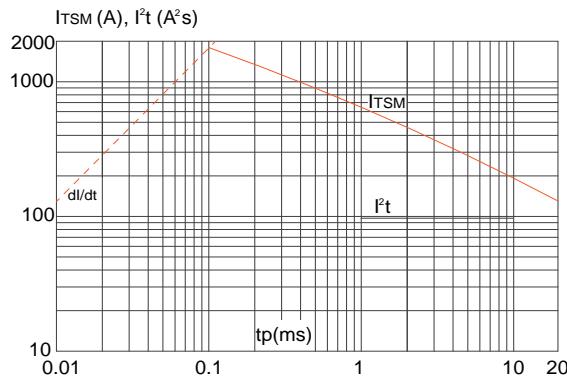
**FIG4**

On-state characteristics (maximum values)



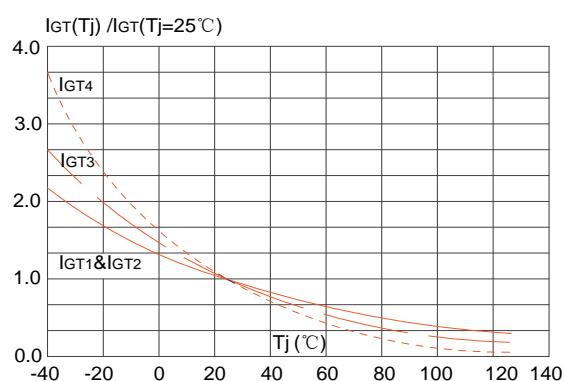
**FIG5**

Non-repetitive surge peak on-state current for a sinusoidal pulse with width  $t_p < 20\text{ms}$ , and corresponding value of  $I^2t$  ( $dI/dt < 100\text{A}/\mu\text{s}$ )



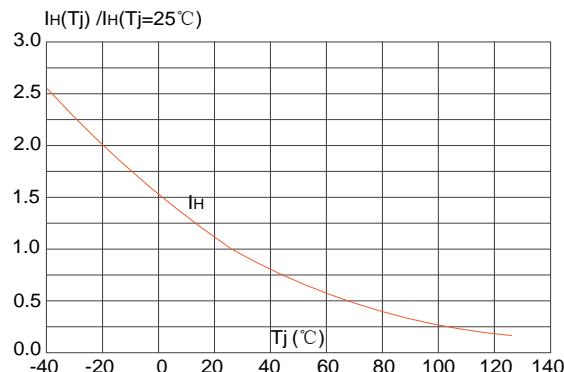
**FIG6**

**FIG.6:** Relative variations of gate trigger current, holding current and latching current versus junction temperature

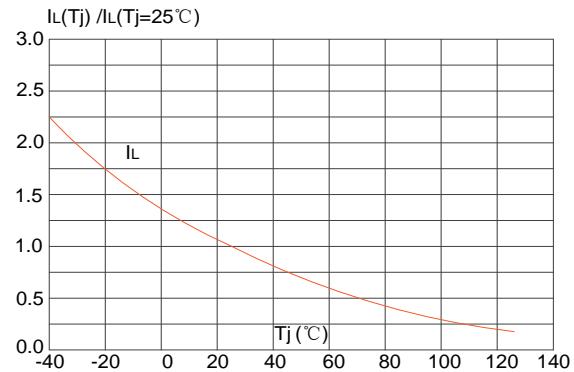


**FIG7**

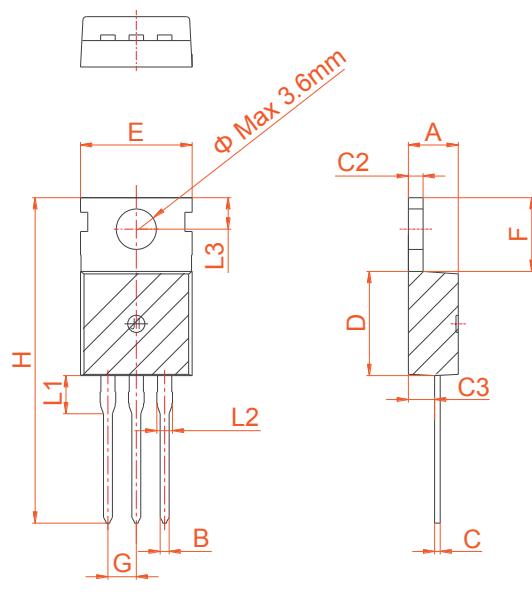
**FIG.7:** Relative variations of holding current versus junction temperature


**FIG8**

**FIG.8:** Relative variations of latching current versus junction temperature

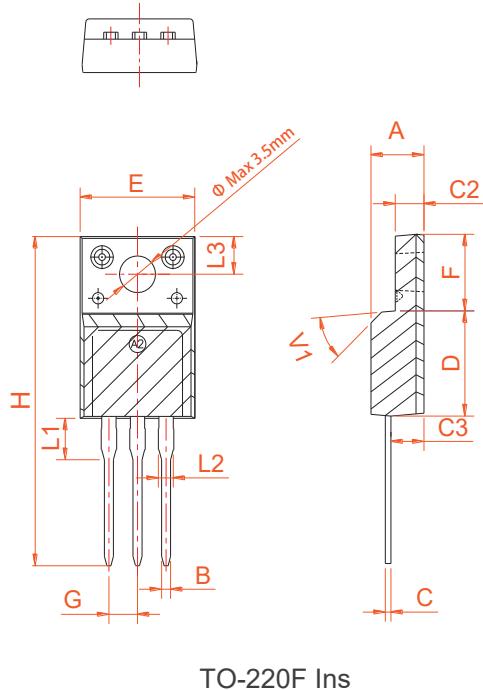


## PACKAGE MECHANICAL DATA



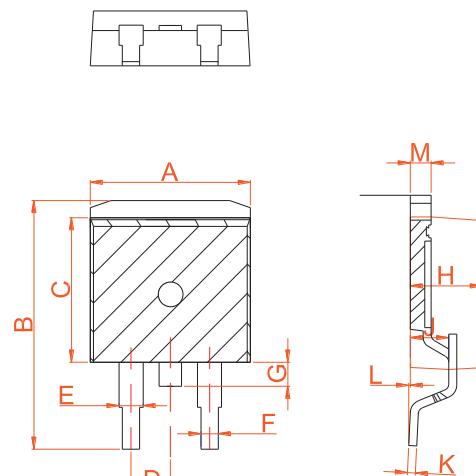
Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	4.40		4.60	0.173		0.181
B	0.70		0.90	0.028		0.035
C	0.45		0.60	0.018		0.024
C2	1.23		1.32	0.048		0.052
C3	2.20		2.60	0.087		0.102
D	8.90		9.90	0.350		0.390
E	9.90		10.3	0.390		0.406
F	6.30		6.90	0.248		0.272
G		2.54			0.1	
H	28.0		29.8	1.102		1.173
L1		3.39			0.133	
L2	1.14		1.70	0.045		0.067
L3	2.65		2.95	0.104		0.116
Φ		3.6			0.142	

## PACKAGE MECHANICAL DATA



Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	4.50			4.90	0.177	
B	0.74	0.80	0.83	0.029	0.031	0.033
C	0.47			0.65	0.019	
C2	2.45			2.75	0.096	
C3	2.60			3.00	0.102	
D	8.80			9.30	0.346	
E	9.80			10.4	0.386	
F	6.40			6.80	0.252	
G		2.54				0.1
H	28.0			29.8	1.102	
L1		3.63				0.143
L2	1.14			1.70	0.045	
L3		3.30				0.130
V1		45°				45°

Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	9.90		10.20	0.390		0.402
B	14.70		15.80	0.579		0.622
C	9.4		9.6	0.37		0.378
D		2.54		0.100		
E	1.20		1.40	0.047		0.055
F	0.75		0.85	0.029		0.033
G		1.75				0.069
H	4.40		4.70	0.173		0.185
J	2.30		2.70	0.091		0.106
K	0.38		0.55	0.015		0.022
L	0	0.10	0.25	0	0.004	0.010
M	1.25		1.35	0.049		0.053





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